

8-Bit Equality Comparator

The TC74HCT688A is a high speed CMOS 8-BIT EQUALITY COMPARATOR fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

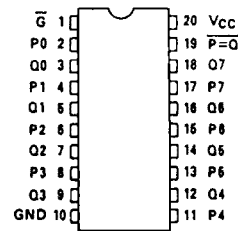
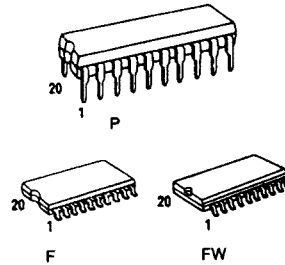
The TC75HCT688A compares two 8-bit binary or BCD words applied inputs P₀ ~ P₇, and inputs Q₀ ~ Q₇, and indicates whether or not they are equal.

A signal active low enable is provided to facilitate cascading of several packages to compare of words greater than 8 bits.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

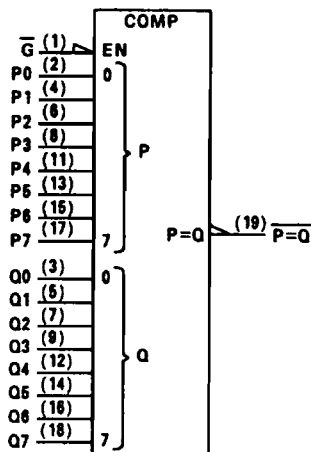
Features

- High Speed: $t_{pd} = 17\text{ns(Typ.)}$ at $V_{CC} = 5\text{V}$
- Low Power Dissipation: $I_{CC} = 4\mu\text{A(Max.)}$ at $T_a = 25^\circ\text{C}$
- Compatible with TTL outputs: $V_{IH} = 2\text{V(Min.)}$
 $V_{IL} = 0.8\text{V(Max.)}$
- Output Drive Capability: 10 LSTTL Loads
- Symmetrical Output Impedance: $|I_{OH}| = I_{OL} = 4\text{mA(Min.)}$
- Balanced Propagation Delays: $t_{pLH} = t_{pHL}$
- Pin and Function Compatible with 74LS688



(TOP VIEW)

Pin Assignment



IEC Logic Symbol

Truth Table

Inputs		Output
P, Q	G	$\overline{P=Q}$
$P=Q$	L	L
$P\neq Q$	L	H
X	H	H

X: "Don't Care"

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Supply Voltage Range	V_{CC}	-0.5 - 7	V

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
DC Input Voltage	V_{IN}	$-0.5 - V_{CC} + 0.5$	V
DC Output Voltage	V_{OUT}	$-0.5 - V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 25	mA
DC V_{CC} /Ground Current	I_{CC}	± 50	mA
Power Dissipation	P_D	500(DIP)*180(SOIC)	mW
Storage Temperature	T_{stg}	-65 - 150	°C
Lead Temperature 10sec	T_L	300	°C

*500mW in the range of $T_a = -40^\circ\text{C} - 65^\circ\text{C}$. From $T_a = 65^\circ\text{C}$ to 85°C a derating factor of $-10\text{mW}/^\circ\text{C}$ shall be applied until 300mW.

Recommended Operating Conditions

Parameter	Symbol	Value	Unit
Supply Voltage	V_{CC}	4.5 - 5.5	V
Input Voltage	V_{IN}	$0 - V_{CC}$	V
Output Voltage	V_{OUT}	$0 - V_{CC}$	V
Operating Temperature	T_{opr}	-40 - 85	°C
Input Rise and Fall Time	t_r, t_f	0 - 500	ns

DC Electrical Characteristics

Parameter	Symbol	Test Condition	V_{CC}	$T_a = 25^\circ\text{C}$			$T_a = -40 - 85^\circ\text{C}$		Unit	
				Min.	Typ.	Max.	Min.	Max.		
High-Level Input Voltage	V_{IH}	-	4.5 f 5.5	2.0	-	-	2.0	-	V	
Low-Level Input Voltage	V_{IL}	-	4.5 f 5.5	-	-	0.8	-	0.8	V	
High-Level Output Voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -20\mu\text{A}$	4.5	4.4	4.5	-	4.4	-	V
			$I_{OH} = -4\text{mA}$	4.5	4.18	4.31	-	4.13	-	
Low-Level Output Voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 20\mu\text{A}$	4.5	-	0.0	0.1	-	0.1	V
			$I_{OL} = 4\text{mA}$	4.5	-	0.17	0.26	-	0.33	
Input Leakage Current	I_{IN}	$V_{IN} = V_{CC}$ or GND	5.5	-	-	± 0.1	-	± 1.0	μA	
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND	5.5	-	-	1.0	-	10.0	mA	
	ΔI_{CC}	Per input: $V_{IN} = 0.5\text{V}$ or 2.4V Other input: V_{CC} or GND	5.5	-	-	2.0	-	2.9		

AC Electrical Characteristics (C_L = 15pF, V_{CC} = 5V, Ta = 25°C)

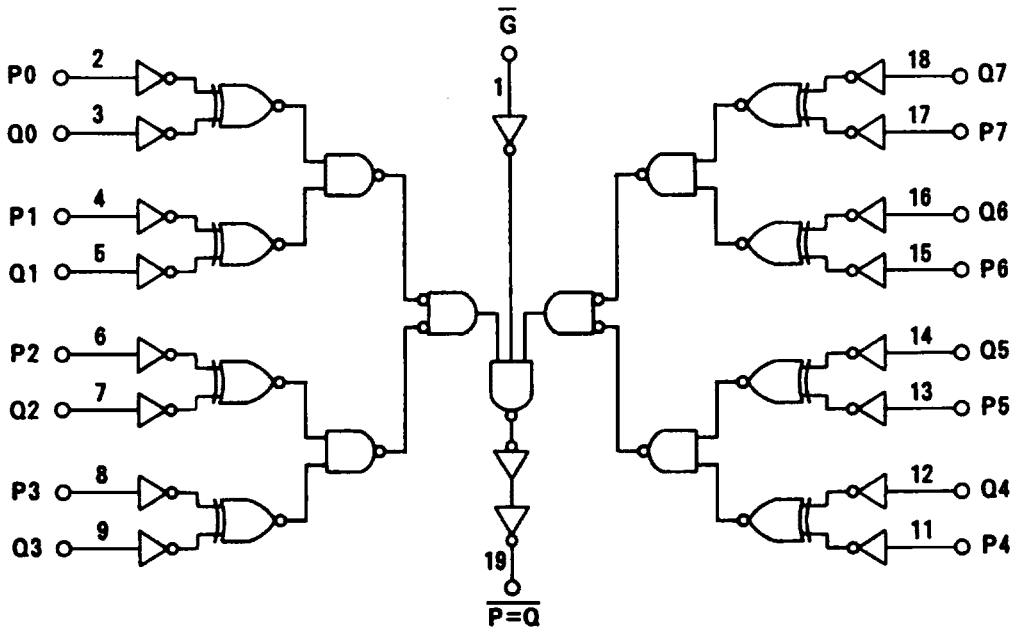
Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Output Transition Time	t _{TLH} t _{THL}	-	-	6	12	ns
Propagation Delay Time (Pn, Qn-P=Q)	t _{pLH} t _{pHL}	-	-	17	27	
Propagation Delay Time (G-P=Q)	t _{pLH} t _{pHL}	-	-	12	19	

AC Electrical Characteristics (C_L = 50pF, Input t_r = t_f = 6ns)

Parameter	Symbol	Test Condition	Ta = 25°C			Ta = -40 ~ 85°C		Unit	
			V _{CC}	Min.	Typ.	Max.	Min.		Max.
Output Transition Time	t _{TLH} t _{THL}	-	4.5	-	8	15	-	19	ns
			5.5	-	7	13	-	16	
Propagation Delay Time (Pn, Qn-P=Q)	t _{pLH} t _{pHL}	-	4.5	-	21	32	-	40	
			5.5	-	18	29	-	36	
Propagation Delay Time (G-P=Q)	t _{pLH} t _{pHL}	-	4.5	-	15	23	-	28	
			5.5	-	13	21	-	26	
Input Capacitance	C _{IN}	-	-	5	10	-	10	pF	
Power Dissipation Capacitance	C _{PD} (1)	-	-	32	-	-	-		

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$



Logic Diagram